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High Performance Schottky Rectifier, 2 x 15 A



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 15 A			
V _R	45 V			
V _F at I _F	See Electrical table			
I _{RM} max.	100 mA at 125 °C			
T _J max.	150 °C			
E _{AS}	10 mJ			
Package	TO-220AB 3L			
Circuit configuration	Common cathode			

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL CHARACTERISTICS VALUES					
I _{F(AV)}	Rectangular waveform (per device)	30	А		
V _{RRM}		35/45	V		
I _{FRM}	$T_{\rm C} = 123 \ ^{\circ}{\rm C}$ (per leg)	30			
IFSM	t _p = 5 μs sine	1020	A		
V _F	20 A _{pk} , T _J = 125 °C	0.6	V		
TJ	Range	-65 to +150	°C		

VOLTAGE RATINGS					
PARAMETER SYMBOL VS-MBR3045CT-M3 UNITS					
Maximum DC reverse voltage	V _R	45	M		
Maximum working peak reverse voltage	V _{RWM}	45	V		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL TEST CONDITIONS		VALUES	UNITS	
Maximum average forward per leg		T 100 00 all div		15	
current per device	F(AV)	T_{C} = 123 °C, rated V_{R}		30	
Peak repetitive forward current per leg	repetitive forward current per leg I_{FRM} Rated V_R , square wave, 20 kHz, T_C = 123 °C		30		
Non-repetitive peak surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1020	A
	1 OM	Surge applied at rated load conditions halfwave, single phase, 60 Hz		200	
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 5 mH		10	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		2	А

Revision: 28-Feb-2023

1



Vishay Semiconductors

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
		30 A	T _J = 25 °C	0.76		
Maximum forward voltage drop	V _{FM} ⁽¹⁾	20 A	T _J = 125 °C	0.6	V	
		30 A	1j = 125 C	0.72		
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	1	mA	
Maximum instantaneous reverse current		T _J = 125 °C	Raled DC vollage	100		
Threshold voltage	V _{F(TO)}			0.29	V	
Forward slope resistance	r _t	$T_{J} = T_{J}$ maximum		13.6	mΩ	
Maximum junction capacitance	CT	V_{R} = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 $^{\circ}\mathrm{C}$		800	pF	
Typical series inductance	L _S	Measured from top of terminal to mounting plane		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	

Note

 $^{(1)}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	e T _J		-65 to +150	°C	
Maximum storage temperature range	e T _{Stg}		-65 to +175		
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.5		
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased Only for TO-220	0.50	°C/W	
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation For D ² PAK and TO-262	50		
Approvimete weight			2	g	
Approximate weight			0.07	oz.	
	imum	Non-lubricated threads	6 (5)	kgf ⋅ cm	
Mounting torque max	imum		12 (10)	(lbf · in)	
Marking device		Case style TO-220AB 3L	MBR3	MBR3045CT	



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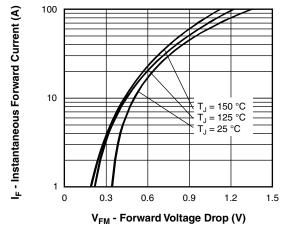


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

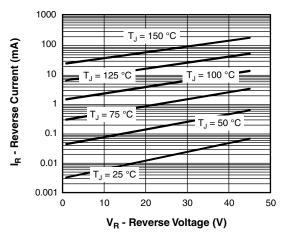


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

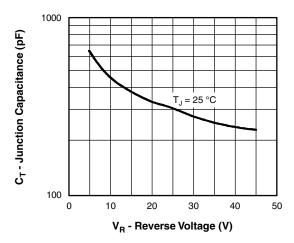
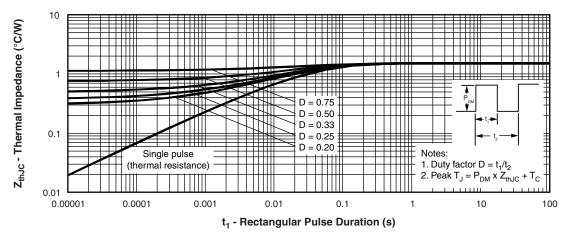
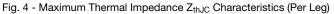


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)





 Revision: 28-Feb-2023
 3
 Document Number: 96257

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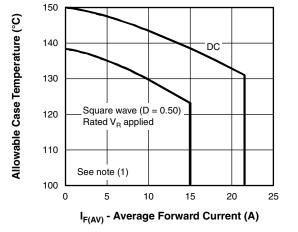


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

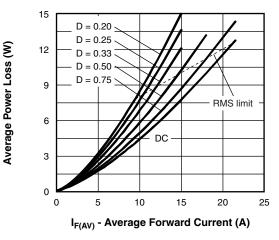


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

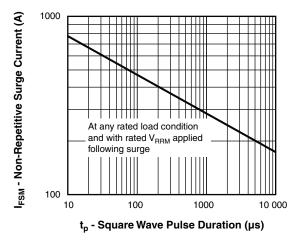


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

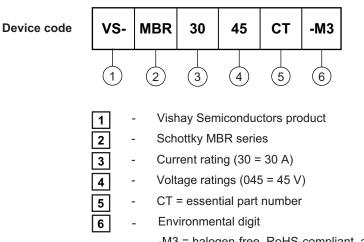
Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);}$ $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D); I_R \text{ at } V_{R1} = rated V_R$



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ORDERING INFORMATION TABLE



-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	REFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION				
VS-MBR3045CT-M3	50	Antistatic plastic tubes			

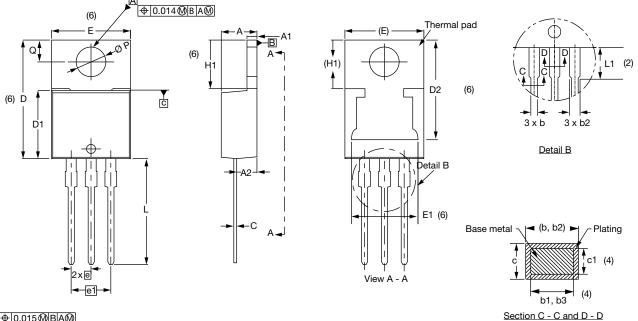
LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?96154				
Part marking information	www.vishay.com/doc?95028			



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TO-220AB 3L

DIMENSIONS in millimeters and inches



⊕0.015@BA@



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

MILLIMETERS	INCHES

Conforms to JEDEC[®] outline TO-220AB

SYMBOL				INCITEO	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
Е	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Notes

 $^{(1)}\,$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only

(5) Controlling dimensions: inches

⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1

⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

Revision: 22-Feb-2024

1



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Revision: 01-Jul-2024